

Description

The Edge4707B is a precision measurement unit designed for automatic test equipment and instrumentation. Manufactured in a wide voltage CMOS process, it is a monolithic solution for a quad channel per pin PMU.

Each channel of the Edge4707B features a PMU that can force or measure voltage over a 15V I/O range, and supports 4 current ranges: 2 μ A, 200 μ A, 20 μ A, and 2 mA.

Each channel of the Edge4707B features an on-board window comparator that provides two bits of information: DUT too high and DUT too low. There is also a monitor function which provides a real time analog signal proportional to either the measured voltage or current.

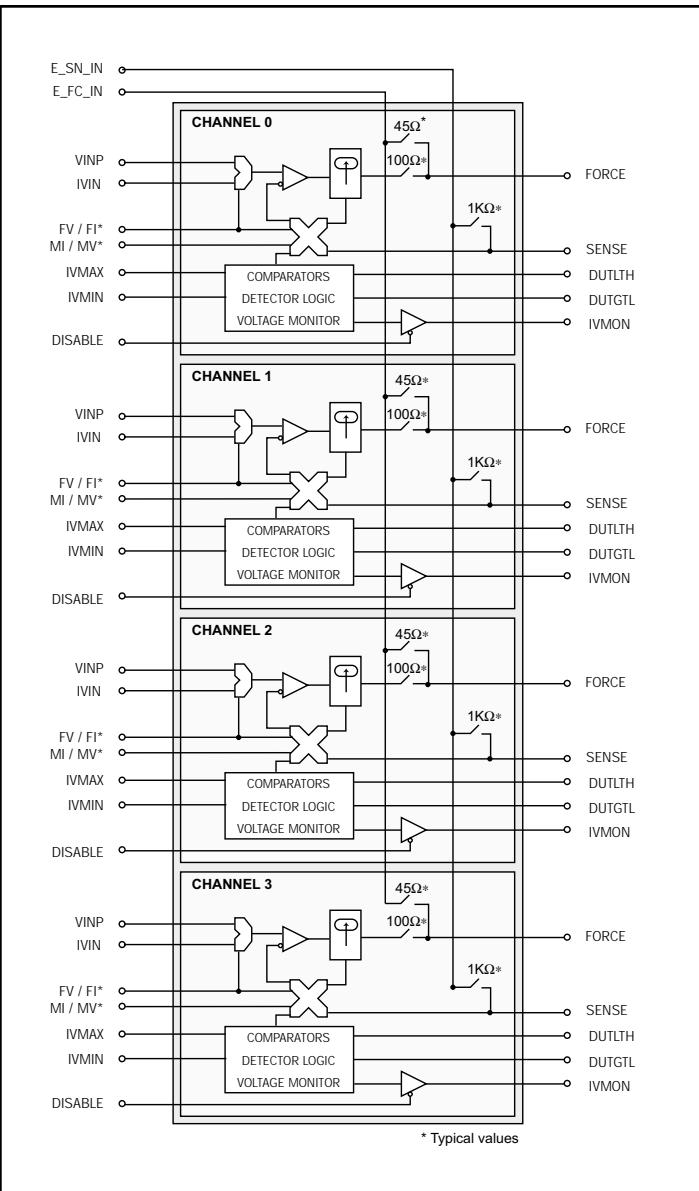
The Edge4707B is designed to be a low power, low cost, small footprint solution to allow high pin count testers to support a PMU per pin.

In addition, two independent switches per channel (for a central PMU force and sense) plus two wide voltage analog muxes per channel are included.

Features

- FV / MI Capability
- FI / MV Capability
- FV / MV Capability
- FI / MI Capability
- 4 Current Ranges (2 μ A, 20 μ A, 200 μ A, 2mA)
- -2V to +13V Output Range (Zero Current)
- 0V to 11V Output Range (Full Scale Current)
- FV Linearity to $\pm .025\%$ FSR
- Central PMU Switches
- Per Pin Super Voltage Switches

Functional Block Diagram



Applications

- Automated Test Equipment
 - Memory Testers
 - VLSI Testers
 - Mixed Signal Tester

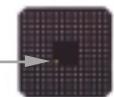
TEST AND MEASUREMENT PRODUCTS
PIN Description

Pin Name	Pin #	Description
VINP[0:3]	C2, F5, H3, L2	Analog voltage input which forces the output voltage (FV/MI mode) (one per channel).
IVIN[0:3]	C1, F2, H4, J5	Analog voltage input which forces the output current (FI/MV mode) (one per channel).
FORCE[0:3]	C14, F12, H13, L12	Analog output pin which forces current or voltage.
SENSE[0:3]	C13, G10, H14, K11	Analog input pin which senses voltage.
FV/FI*[0:3]	D10, B8, A6, E6	TTL compatible input which determines whether the PMU is forcing voltage or forcing current.
MI/MV*[0:3]	B10, A8, C6, D5	TTL compatible input which determines whether the PMU is measuring current or measuring voltage.
RS0[0:3] RS1[0:3]	B11, A9, C7, C5 A12, C10, D8, A5	TTL compatible current range select inputs.
IVMIN[0:3] IVMAX[0:3]	G5, E1, H2, K3 C3, E3, H1, L1	Analog input voltages which establish the lower and upper threshold level for the measurement comparator.
DUTLTH[0:3] DUTGTL[0:3]	P11, N9, N7, N5 N11, P9, P7, P5	Digital comparator output that indicates the DUT measurement is less than the upper threshold and greater than the lower threshold.
DISABLE[0:3]	A11, C9, D7, A4	TTL compatible input which places the IVMON outputs in high impedance.
E_SNSEL[0:3]	D11, E9, B7, B5	TTL switch select for the external SENSE switch for Channels 0–3.
E_SN_IN	L4	Analog output for external SENSE.
E_FC_IN	K5	Analog input for external FORCE signal.
E_FCSEL[0:3]	E10, B9, A7, D6	TTL switch select for the external FORCE switch for Channels 0–3.
I_FCSEL[0:3]	C11, D9, B6, B4	TTL switch select for internal FORCE switch for Channels 0–3.
RA[0:3], RB[0:3] RC[0:3], RD[0:3]	D13, G11, J14, K10 D14, G12, J13, L11 E12, G14, J10, M14 F11, G13, K12, M13	External resistor input corresponding to Ranges A through D.
RES_IN[0:3]	F10, F13, J12, L13	External resistor input. One side of the external resistors connect to RA[0:3], RB[0:3], RC[0:3], RD[0:3]. The other side of all resistors connect to RES_IN.

TEST AND MEASUREMENT PRODUCTS
PIN Description (*continued*)

Pin Name	Pin #	Description
IVMON[0:3]	B1, E2, G4, J4	Analog voltage output that provides a real time monitor of either the measured voltage or measured current level.
COMP1[0:3] COMP2[0:3]	D4, F1, J2, K4 E5, F3, J1, M1	Internal compensation pins that require an external capacitor connected between the two pins.
COMP3[0:3]	D2, F4, J3, M2	Internal compensation pin that requires an external capacitor connected between the pin and ground.
COMP4[0:3]	D1, G2, H5, L3	Internal compensation pin that requires an external capacitor connected between the pin and the RES_IN pin.
N/C	A2, A13, A14, B2, B3, B12, B13, B14, C4, C12, H10, K7, M3, M11, N2, N3, N12, N13, N14, P1, P2, P12, P13, P14	Not connected.
<i>Analog MUX Switches</i>		
VIH[0:3]	K9, M9, M7, M5	Driver High input.
VIHH[0:3]	L10, K8, L7, K6	Super voltage input High.
VIL[0:3]	L9, M8, M6, M4	Driver Low input.
VILH[0:3]	M10, L8, L6, L5	Super voltage input Low.
SVSEL[0:3]	A10, C8, E7, A3	Select for MUX.
DVH[0:3]	P10, N8, N6, N4	Output High.
DVL[0:3]	N10, P8, P6, P4	Output Low.
<i>Power Pins</i>		
VCC[1:4]	A1, D12, E4, E14, G3, H12, K2, K13	Positive analog power supply.
VDD	P3	Positive digital supply.
VEE[1:4]	D3, E13, G1, H11, K1, K14, M12, N1	Negative analog power supply.
GND[1:4]	E11, F14, J11, L14	Ground.

TEST AND MEASUREMENT PRODUCTS
PIN Description (continued)
Bottom View

A1 Ball Pad
Indicator


12 mm X 12 mm 180 FLEXBGA

	P1	P2	P3	P4	P5	P6	P7	P8	P9	P10	P11	P12	P13	P14
P	N/C	N/C	VDD	DVL3	DUTGTL3	DVL2	DUTGTL2	DVL1	DUTGTL1	DVHO	DUTLTHO	N/C	N/C	N/C
N	N1 VEE4	N2 N/C	N3 N/C	N4 DVH3	N5 DUTLTH3	N6 DVH2	N7 DUTLTH2	N8 DVH1	N9 DUTLTH1	N10 DVLO	N11 DUTGTL0	N12 N/C	N13 N/C	N14 N/C
M	M1 COMP2_3	M2 COMP3_3	M3 N/C	M4 VIL3	M5 VIH3	M6 VIL2	M7 VIH2	M8 VIL1	M9 VIH1	M10 VILH0	M11 N/C	M12 VEE4	M13 RD3	M14 RC3
L	L1 IVMAX3	L2 VINP3	L3 COMP4_3	L4 E_SN_IN	L5 VILH3	L6 VILH2	L7 VIHH2	L8 VILH1	L9 VILO	L10 VIHH0	L11 RB3	L12 FORCE3	L13 RESIN3	L14 GND4
K	K1 VEE3	K2 VCC4	K3 IVMIN3	K4 COMP1_3	K5 E_FC_IN	K6 VIHH3	K7 VIHH1	K8 VIHO	K9 RA3	K10 SENSE3	K11 RD2	K12 VCC4	K13 VEE3	K14 VCC4
J	J1 COMP2_2	J2 COMP1_2	J3 COMP3_2	J4 IVMON3	J5 IVIN3	A1 Ball Pad Corner Indicator (No Solder Ball)				J10 RC2	J11 GND3	J12 RESIN2	J13 RB2	J14 RA2
H	H1 IVMAX2	H2 IVMIN2	H3 VINP2	H4 IVIN2	H5 COMP4_2	A1 Ball Pad Corner Indicator (No Solder Ball)				H10 O	H11 O	H12 O	H13 O	H14 O
G	G1 VEE2	G2 COMP4_1	G3 VCC3	G4 IVMON2	G5 IVMINO	G6 F6	G7 F7	G8 F8	G9 F9	G10 SENSE1	G11 RA1	G12 RB1	G13 RD1	G14 RC1
F	F1 COMP1_1	F2 IVIN1	F3 COMP2_1	F4 COMP3_1	F5 VINP1	A1 Ball Pad Corner Indicator (No Solder Ball)				F10 RESINO	F11 RDO	F12 FORCE1	F13 RESIN1	F14 GND2
E	E1 IVMIN1	E2 IVMON1	E3 IVMAX1	E4 VCC2	E5 COMP2_0	E6 FV/FI*3	E7 SVSEL2	E8 E_SNSEL1	E9 E_FCSEL0	E10 GND1	E11 RC0	E12 VEE1	E13 VCC2	E14 VCC2
D	D1 COMP4_0	D2 COMP3_0	D3 VEE1	D4 COMP1_0	D5 MI/MV*3	D6 E_FCSEL3	D7 DISABLE2	D8 RS1_2	D9 I_FCSEL1	D10 FV/FI*0	D11 E_SNSEL0	D12 VCC1	D13 RAO	D14 RBO
C	C1 IVINO	C2 VINPO	C3 IVMAXO	C4 N/C	C5 RSO_3	C6 MI/MV*2	C7 RSO_2	C8 SVSEL1	C9 DISABLE1	C10 RS1_1	C11 I_FCSEL0	C12 N/C	C13 SENSEO	C14 FORCEO
B	B1 IVMONO	B2 N/C	B3 N/C	B4 I_FCSEL3	B5 E_SNSEL3	B6 I_FCSEL2	B7 E_SNSEL2	B8 FV/FI*1	B9 E_FCSEL1	B10 MI/MV*0	B11 RSO_0	B12 N/C	B13 N/C	B14 N/C
A	A1 VCC1	A2 N/C	A3 SVSEL3	A4 DISABLE3	A5 RS1_3	A6 FV/FI*2	A7 E_FCSEL2	A8 MI/MV*1	A9 RSO_1	A10 SVSEL0	A11 DISABLE0	A12 RS1_0	A13 N/C	A14 N/C
	1	2	3	4	5	6	7	8	9	10	11	12	13	14

TEST AND MEASUREMENT PRODUCTS
PIN Description (continued)

A1 Ball Pad
Indicator

Top View

12 mm X 12 mm 180 FLEXBGA

	A1	A2	A3	A4	A5	A6	A7	A8	A9	A10	A11	A12	A13	A14
A	VCC1	N/C	SVSEL3	DISABLE3	RS1_3	FV/FI*2	E_FCSEL2	MI/MV*1	RS0_1	SVSELO	DISABLEO	RS1_0	N/C	N/C
B	IVMONO	N/C	N/C	I_FCSEL3	E_SNSEL3	I_FCSEL2	E_SNSEL2	FV/FI*1	E_FCSEL1	MI/MV*0	RS0_0	N/C	N/C	N/C
C	IVINO	VINPO	IVMAXO	N/C	RSO_3	MI/MV*2	RSO_2	SVSEL1	DISABLE1	RS1_1	I_FCSEL0	N/C	SENSEO	FORCEO
D	COMP4_0	COMP3_0	VEE1	COMP1_0	MI/MV*3	E_FCSEL3	DISABLE2	RS1_2	I_FCSEL1	FV/FI*0	E_SNSEL0	VCC1	RAO	RBO
E	IVMIN1	IVMON1	IVMAX1	VCC2	COMP2_0	FV/FI*3	SVSEL2	E_SNSEL1	E_FCSEL0	GND1	RC0	VEE1	VCC2	
F	COMP1_1	IVIN1	COMP2_1	COMP3_1	VINP1	F6	F7	F8	F9	F10	F11	F12	F13	F14
G	G1	G2	G3	G4	G5	G6	G7	G8	G9	G10	G11	G12	G13	G14
H	IVMAX2	IVMIN2	VINP2	IVIN2	COMP4_2	H6	H7	H8	H9	H10	H11	H12	H13	H14
J	COMP2_2	COMP1_2	COMP3_2	IVMON3	IVIN3	J6	J7	J8	J9	J10	J11	J12	J13	J14
K	KEE3	VCC4	IVMIN3	COMP1_3	E_FC_IN	K6	K7	K8	K9	K10	K11	K12	K13	K14
L	IVMAX3	VINP3	COMP4_3	E_SN_IN	VILH3	L6	L7	L8	L9	L10	L11	L12	L13	L14
M	COMP2_3	COMP3_3	N/C	VIL3	VIH3	M6	M7	M8	M9	M10	M11	M12	M13	M14
N	VEE4	N/C	N/C	DVH3	DUTLTH3	N6	N7	N8	N9	N10	N11	N12	N13	N14
P	N/C	N/C	VDD	DVL3	DUTGTL3	P6	P7	P8	P9	P10	P11	P12	P13	P14

1 2 3 4 5 6 7 8 9 10 11 12 13 14

TEST AND MEASUREMENT PRODUCTS

Circuit Description

Circuit Overview

The Edge4707B is a quad channel parametric test and measurement unit that can :

- Force Voltage / Measure Current
- Force Current / Measure Voltage
- Force Voltage / Measure Voltage
- Force Current / Measure Current

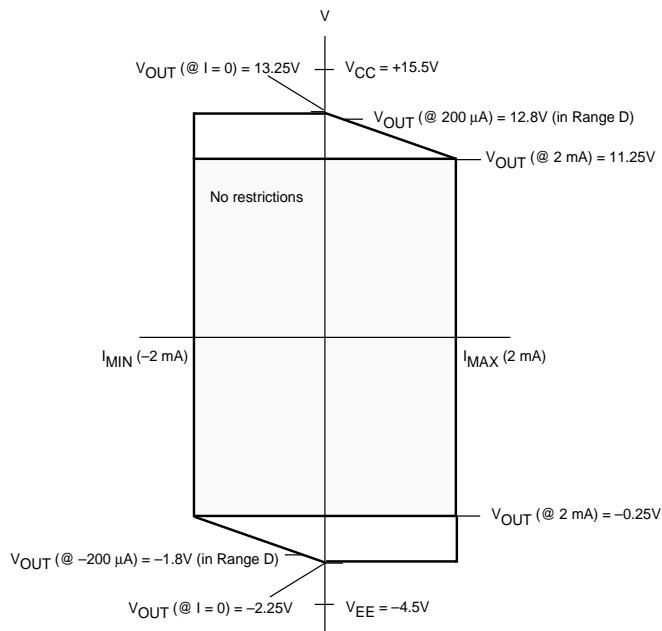
Each PMU channel can force or measure voltage over a 15V range and force or measure current over four distinct ranges:

- $\pm 2 \mu\text{A}$
- $\pm 20 \mu\text{A}$
- $\pm 200 \mu\text{A}$
- $\pm 2 \text{ mA}$.

An on-board window comparator provides two bit output range classification. Also, a monitor passes a real time analog voltage which tracks either the measured current or voltage.

PPMU Functionality

The trapezoid in Figure 1 describes the current-voltage functionality of the PMU with $V_{CC} = 15.5\text{V}$ and $V_{EE} = -4.5\text{V}$, *in Range D*.



NOTE: Negative current implies current is flowing into the 4707 from DUT.

Figure 1. PMU Functionality

Control Inputs

FV/FI* is a TTL compatible input which determines whether the PMU forces voltage or current, and MI/MV* is a TTL compatible input which determines whether the PMU measures current or voltage. FV/FI* and MI/MV* are independent for each PMU. Table 1 describes the modes of operation controlled by these pins.

FV / FI*	MI/MV*	Mode of Operation
0	0	Force Current, Measure Voltage
0	1	Force Current, Measure Current
1	0	Force Voltage, Measure Voltage
1	1	Force Voltage, Measure Current

Table 1.

RS0 and RS1 are TTL compatible inputs to an internal analog mux which selects an external resistor corresponding to a desired current range. The truth table for RS0 to RS1, along with the associated external resistor values and current ranges, is shown in Table 2. RS0 and RS1 are independent for each channel of the 4707B.

RS1	RS0	Range	Current Range	"Nominal" Ext. R
0	0	A	$\pm 2 \mu\text{A}$	$R_A = 1\text{M}\Omega$
0	1	B	$\pm 20 \mu\text{A}$	$R_B = 100\text{k}\Omega$
1	0	C	$\pm 200 \mu\text{A}$	$R_C = 10\text{k}\Omega$
1	1	D	$\pm 2 \text{ mA}$	$R_D = 1\text{k}\Omega$

Table 2.

FORCE/SENSE

FORCE is an analog output which either forces a current or forces a voltage, depending on which operating mode is selected.

SENSE is a high impedance analog input which measures the DUT voltage input in the MV operating mode.

FORCE and SENSE are brought out to separate pins to allow remote sensing.

TEST AND MEASUREMENT PRODUCTS

Circuit Description (*continued*)

IVMON

IVMON is a real time analog voltage output which tracks the sensed parameter.

In the MV mode, the output voltage displayed at IVMON is a 1:1 mapping of the SENSE voltage. In the MI mode, IVMON follows the equation:

$$\text{IVMON} = \text{I(measured)} * \text{REXT}$$

Using nominal values for the external resistors (RA, RB, RC, and RD), a voltage at IVMON of +2V corresponds to Imax and -2V corresponds to Imin of the selected current range.

The IVMON pin can also be placed into a high impedance state by using the DISABLE input (see Table 3).

Disable	MI / MV*	Sensed Parameter
1	X	High Impedance
0	0	Measured Voltage
0	1	Measured Current

Table 3.

Force Current Mode

In the FI mode ($\text{FV/FI}^* = 0$), IVIN is a high impedance analog voltage input that is converted into a current at the FORCE pin using the following relationship:

$$\text{Forced Current} = \text{IVIN} / \text{REXT}$$

(Positive current is defined as current flowing out of the FORCE pin.) The IVIN input voltage range and forced current (at FORCE) can be seen in Table 4.

IVIN	Corresponding Forced Current
+2V	Imax (full scale)
0V	0
-2V	Imin (full scale)

Table 4.

Measure Voltage Mode

In the MV mode ($\text{MI/MV}^* = 0$), DUT voltage is measured via the SENSE input pin. Note that EXT_SENSE_SEL = 0 when the Edge4707B SENSE is used. This measured voltage is also tested with the on-board window comparator.

Comparator

The Edge4707B features an on-board window comparator which provides two-bit measurement range classification. IVMAX and IVMIN are high impedance analog inputs that establish the upper and lower thresholds for the window comparator.

In the MI mode, an I/V MAX input of +2V will set the upper threshold of the window comparator to a voltage corresponding to +FSC (full-scale current), and an I/V MIN input of -2V will set the lower threshold to a voltage corresponding to -FSC (positive current is defined as current flowing out of the PMU).

DUTGTL the DUTLTH are LVTTL compatible outputs which indicate the range of the measured parameter in relation to IVMIN and IVMAX. Comparator functionality is summarized in Table 5 for MI Mode and Table 6 for MV mode.

Force Voltage Mode

In the FV mode ($\text{FV/FI}^* = 1$), VINP is a high impedance analog voltage input that maps directly to the voltage forced at the FORCE pin.

Measure Current Mode

In the MI mode ($\text{MI/MV}^* = 1$), a current monitor is connected in series with the PMU forcing amplifier. This monitor generates a voltage that is proportional to the current passing through it, and is brought out to IVMON. This voltage (corresponding to the measured current) is also tested by the on-board window comparator.

TEST AND MEASUREMENT PRODUCTS
Circuit Description (*continued*)

TEST CONDITION	DUT LTH	DUT GTL
IVMON > IVMAX IVMON < IVMAX	0 1	N/A
IVMON > IVMIN IVMON < IVMIN	N/A	1 0
IVMON < IVMAX and IVMON > IVMIN	1	1

Table 5. MI Comparator Truth Table

TEST CONDITION	DUT LTH	DUT GTL
SENSE > IVMAX SENSE < IVMAX	0 1	N/A
SENSE > IVMIN SENSE < IVMIN	N/A	1 0
SENSE < IVMAX and SENSE > IVMIN	1	1

Table 6. MV Comparator Truth Table

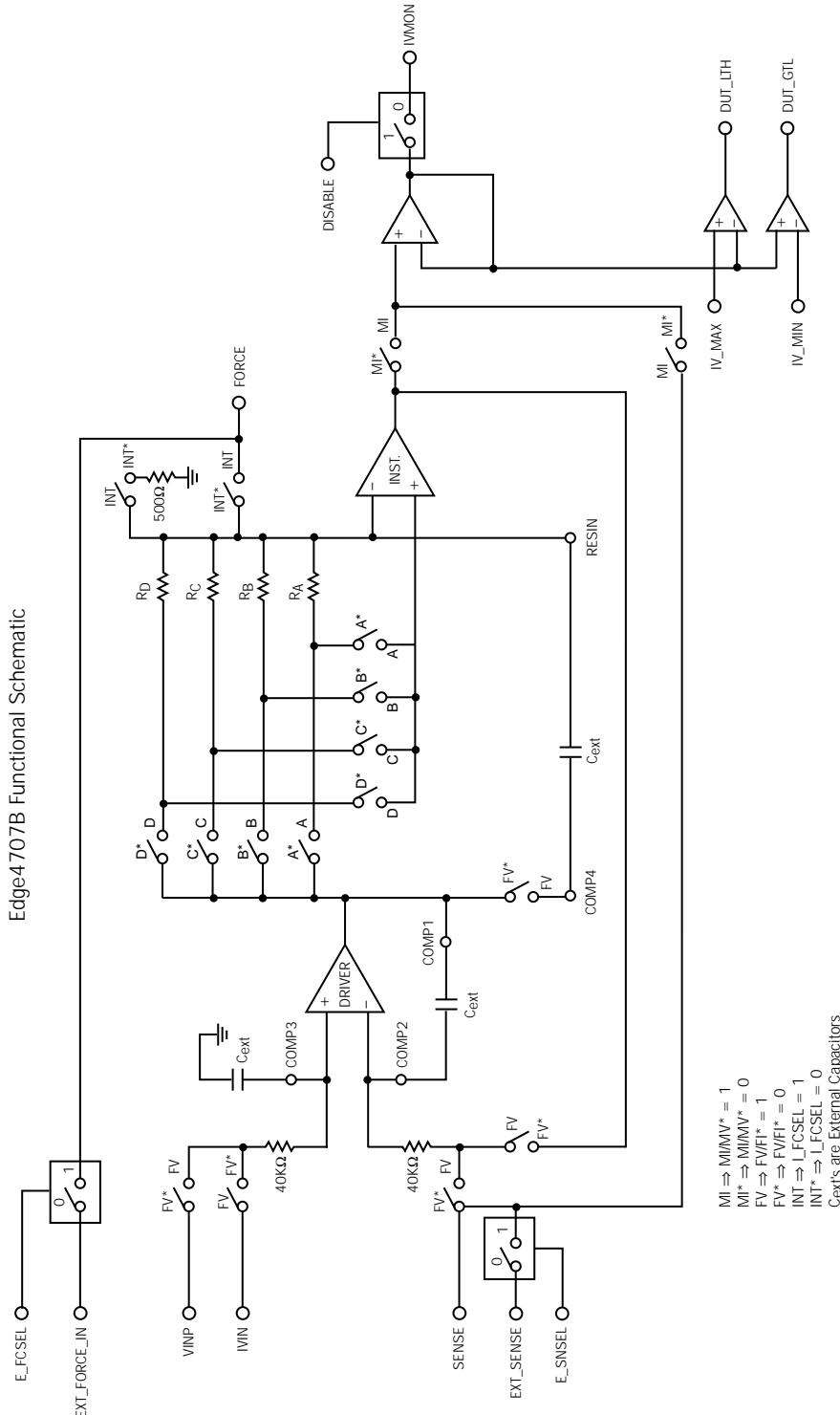


Figure 2. Edge4707B Functional Schematic

TEST AND MEASUREMENT PRODUCTS

Circuit Description (*continued*)

REXT Selection

The Edge 4707B is designed for the voltage drop across RA, RB, RC, and RD to be $\leq 2V$ with the maximum current passing through them. However, these resistor values can be changed to support different applications.

Increasing the maximum current beyond the nominal range is not recommended. However, decreasing the maximum current is allowed by increasing the external resistor using the equation $IMAX = 2V / REXT$.

Switch Operation on Force and Sense Lines

Each channel of the Edge4707B features two switches connected to the FORCE output pin (External Force = 45Ω , Internal Force = 100Ω) and one $1K\Omega$ switch connected to the SENSE input pin. These switches are controlled by the TTL compatible inputs I_FCSEL, E_FCSEL, and E_SNSEL. Switch operation is described in Table 7.

Switch	Switch Select Name	Open/Close State on Switch
100Ω , to internal force circuitry	I_FCSEL	0 = Open 1 = Closed
45Ω , to external force circuitry	E_FCSEL	0 = Open 1 = Closed
$1K\Omega$, to external sense circuitry	E_SNSEL	0 = Open 1 = Closed

Table 7.

These switches can be configured to route the Edge4707B for external forcing or sensing operations (see Figure 2). For external forcing operation, the switch controlled by I_FCSEL can be used to internally isolate the PMU from the FORCE output. This enables the user to connect the FORCE pin to an external device connected to the E_FC_IN pin using the switch controlled by the E_FC_SEL input. I_FCSEL and E_FCSEL functionality is described in Table 8.

I_FCSEL	E_FCSEL	FORCE
0	0	HIZ
1	1	Illegal Condition
1	0	VINP
0	1	E_FC_IN

Table 8.

For external sense operation, the switch controlled by E_SNSEL can be used to internally connect the SENSE input pin to the E_SN_IN output pin (see Figure 2). This allows the user to use the E_SN_IN pin for remote sensing.

Analog MUX

The Edge4707B has a separate analog mux section which is intended for 12V flash programming signal muxing with lower, more standard voltages. There are five inputs for this section, all of which are brought out to external pins (see Figure 3). The two outputs, DVH and DVL, connect to driver reference voltages of the Edge720 (or other pin electronics drivers).

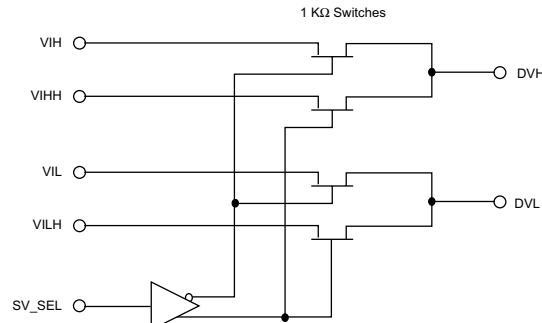


Figure 3. Analog MUX Section

(Typically used to provide flash programming and standard voltages to driver pin electronic references.)

The truth table for SV-SEL is shown in Table 9.

SV_SEL	
0	DVH = VIH DVL = VIL
1	DVH = VIHH DVL = VILH (supervoltage)

Table 9. SV-SEL Truth Table

TEST AND MEASUREMENT PRODUCTS

Circuit Description (*continued*)**Short Circuit Protection**

The Edge 4707B is designed to survive a direct short circuit to any legal voltage at the FORCE and SENSE pins, by virtue of a limited current, which results from the presence of an external current sense resistor (normally 1 K Ω to 1M Ω) in the FORCE path.

Transient Clamps

The Edge 4707B has on-board clamps to limit the voltage and current spikes that might result from either changing the current range or changing the operating mode.

Power Supply Sequencing

In order to avoid the possibility of latch-up, the following power-up requirements must be satisfied:

1. VEE \leq GND \leq VDD \leq VCC at all times
2. VEE \leq All inputs \leq VCC

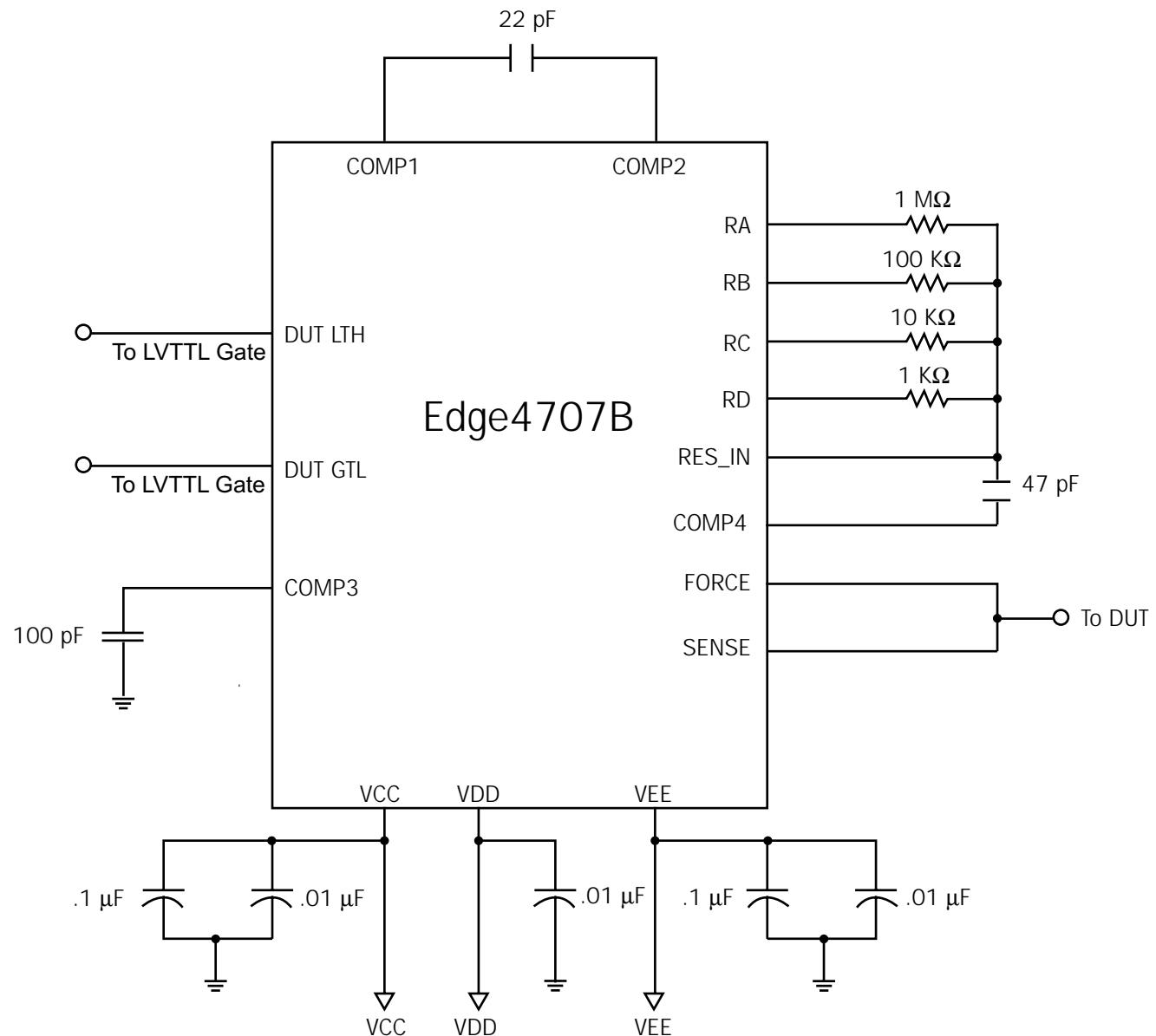
The following power supply sequencing can be used as a guideline when operating the Edge4707:

Power Up Sequence

1. VCC (substrate)
2. VEE/VDD
3. Digital Inputs
4. Analog Inputs

Power Down Sequence

1. Analog Inputs
2. Digital Inputs
3. VEE/VDD
4. VCC (substrate)

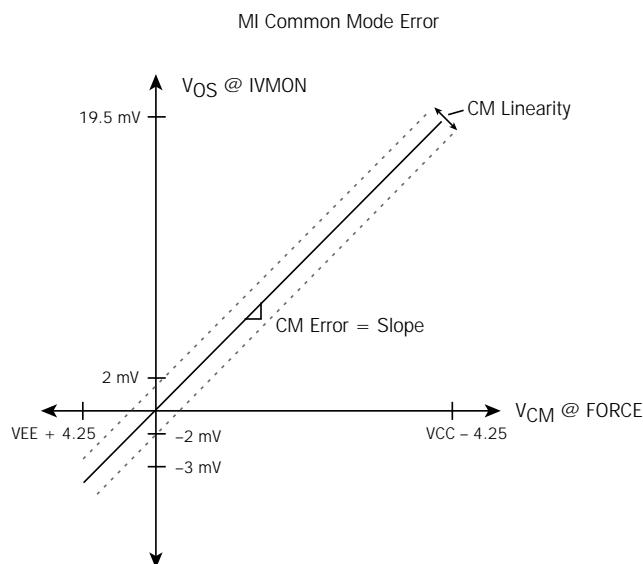
Required External Components (Per Channel)


Actual decoupling and compensation
capacitor values depend on the system environment.

TEST AND MEASUREMENT PRODUCTS
Application Information (*continued*)
Calibration

In order to attain a high degree of accuracy in a typical ATE application, offset and gain errors are accounted for through software calibration. When operating the Edge4707B in the Measure Current (MI) or Force Current (FI) modes, an additional source of error, common mode error, should be accounted for. Common mode error is a measure of how the common mode voltage, V_{CM} , at the input of the current sense amplifier affects the forced or measured current values (see Figure 4). Since this error is created by internal resistors in the current sense amplifier, it is very linear in nature.

Using the common mode error and common mode linearity specifications, one can see that with a small number of calibration steps (see Applications note PMU-A1), the effect of this error can be significantly reduced.



NOTE: In some cases, slope may be negative.

Figure 4. Graphical Representation of Common Mode Error

Maximum Input Voltage Range for FV Mode

In order to ensure that the full-scale output voltage range (FSV) can be achieved by the 4707B, errors such as gain, linearity, and offset must be taken into account when determining the input voltage range required at VINP. The equations in Table 10 can be used to determine the input voltage range required at VINP to achieve full scale voltage (FSV) at the FORCE pin.

VINP (Worst Case)	FORCE
$\frac{FSV}{Gain} + V_{OS} + \text{Linearity Error}$	+ FSV
$\frac{-FSV}{Gain} + V_{OS} + \text{Linearity Error}$	- FSV

Table 10.

Example: If it is desired to operate the 4707B with a FV range of -2V to 13V, the VINP input voltages in Table 11 may be required.

VINP	FORCE
13.3V	+ 13V
-2.13V	-2V

Table 11.

TEST AND MEASUREMENT PRODUCTS
Application Information (*continued*)
Maximum Input Voltage Range for FI Mode

In order to ensure that the full-scale output current range (FSC) can be achieved by the 4707B, errors such as gain, linearity, common mode, and offset must be taken into account when determining the input voltage range required at IVIN. The equations in Table 12 can be used to determine the input voltage range required at IVIN to achieve full scale current (FSC) at the FORCE pin.

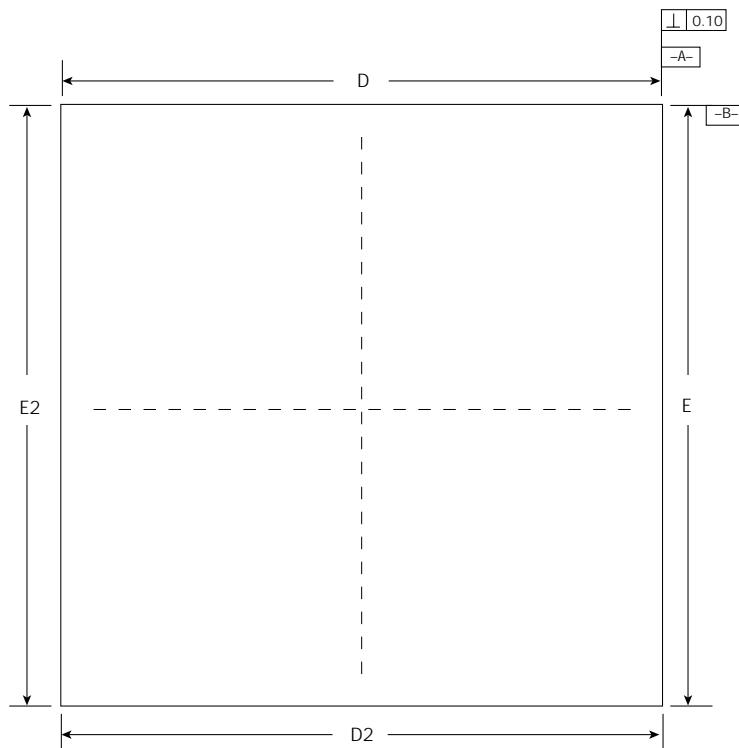
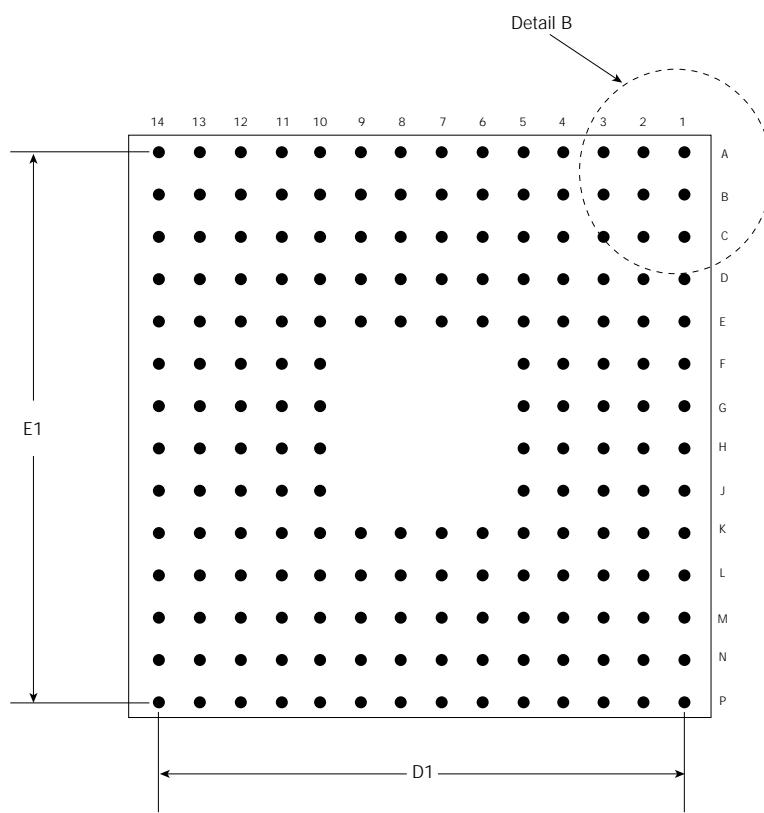
IVIN (Worst Case)	Corresponding Forced Current
$\frac{2V}{\text{Gain}} + V_{OS} + \text{Common Mode Error} + \text{Linearity Error}$	+ FSC
$\frac{-2V}{\text{Gain}} + V_{OS} + \text{Common Mode Error} + \text{Linearity Error}$	- FSC

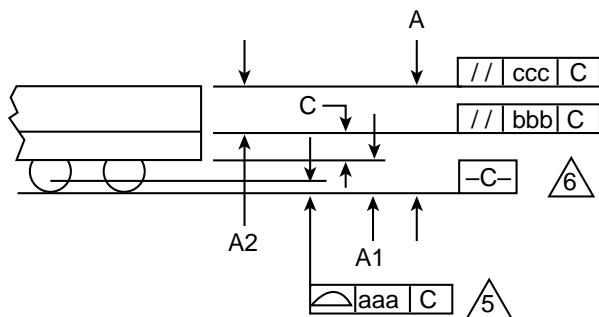
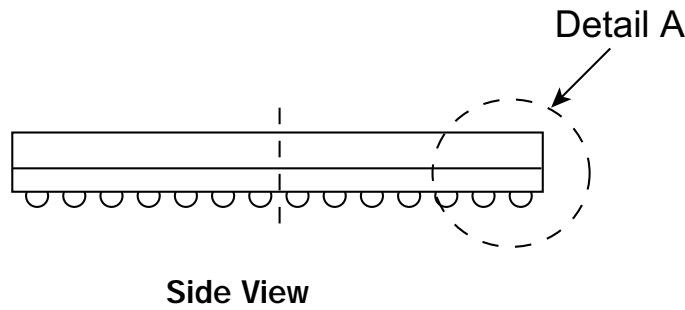
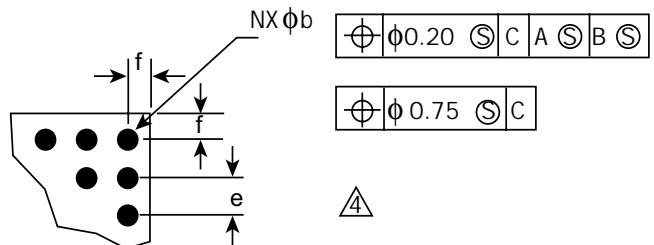
Table 12.

Example: To guarantee that the 4707B is capable of forcing ± 2 mA with $R_{EXT} = 1K\Omega$ (Range D), the input voltages in Table 13 may be required.

IVIN	Corresponding Forced Current
2.15V	2 mA
-2.15V	- 2 mA

Table 13.

TEST AND MEASUREMENT PRODUCTS
Package Information
Top View

Bottom View


TEST AND MEASUREMENT PRODUCTS
Package Information (continued)

Detail A

Detail B
NOTES:

1. All dimensions are in millimeters.
2. 'e' represents the basic solder ball grid pitch.
3. 'M' represents the basic solder ball matrix size, and symbol 'N' is the maximum allowable number of balls after depopulating.
4. 'b' is measurable at the maximum solder ball diameter parallel to primary datum -C-.
5. Dimension 'ccc' is measured parallel to primary datum -C-.
6. Primary datum -C- and seating plane are defined by the spherical crowns of the solder balls.
7. Package surface shall be matte finish charmilles 24 to 27.
8. Package warp shall be 0.050 mm maximum.
9. Substrate material base is BT resin.
10. The overall package thickness 'A' already considers collapse balls.

Dimensional References			
REF.	MIN.	NOM.	MAX.
A	1.30	1.45	1.55
A1	0.30	0.40	0.45
A2	0.65	0.70	0.75
D	11.80	12.00	12.20
D1	10.40 BSC.		
D2	11.80	12.00	12.20
E	11.80	12.00	12.20
E1	10.40 BSC.		
E2	11.80	12.00	12.20
b	0.50	0.55	0.60
c		0.35	
aaa			0.15
bbb			0.20
ccc			0.25
e	0.725	0.80	0.875
f	0.70	0.80	0.90
M	14		
N	180		

TEST AND MEASUREMENT PRODUCTS

Recommended Operating Conditions

Parameter	Symbol	Min	Typ	Max	Units
Positive Analog Power Supply (relative to GND)	VCC	15.25	15.5	15.75	V
Negative Analog Power Supply (relative to GND)	VEE	-4.75	-4.5	-4.25	V
Total Analog Power Supply	VCC – VEE	19.5	20	20.5	V
Digital Power Supply (relative to GND)	VDD	3.15	3.3	3.45	V
Case Temperature	TC	25		65	°C
Thermal Resistance of Package (Junction to Case)	θ _{JC}		4.1		°C/W

Absolute Maximum Ratings

Parameter	Symbol	Min	Typ	Max	Units
Positive Power Supply	VCC			20	V
Negative Power Supply	VEE	-10			V
Total Power Supply	VCC – VEE	0		21	V
Digital Power Supply	VDD	GND – .5		VCC	V
Digital Inputs		-.5		7.0	V
Analog Inputs		VEE – .5		VCC + .5	V
Analog MUX Breakdown Voltage	VI[H, L, HH, LH] – DV[L, H]			VCC – VEE	V
Current Capability of MUX	I _{MUX}	-4.8		4.8	mA
External Force and Sense Switch Breakdown Voltage	E _{FC_IN} – FORCE E _{SN_IN} – FORCE			VCC – VEE	V
Storage Temperature		-55		+125	°C
Junction Temperature		-65		+125	°C
Soldering Temperature				260	°C

Stresses above listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TEST AND MEASUREMENT PRODUCTS
DC Characteristics
Power Supplies

Parameter	Symbol	Min	Typ	Max	Units
Power Supply Consumption (Note 1)					
Positive Supply	ICC			30	mA
Negative Supply	IEE			30	mA
Digital Supply (Quiescent)	IDD			1	mA
Power Supply Rejection Ratio (Notes 2, 3)					
FV/MI Mode	FV/MI PSRR				
FORCE Pin					
@ 100 kHz		20			dB
@ 500 kHz		14			dB
@ 1 MHz		11			dB
IVMON Pin					
@ 100 kHz		14			dB
@ 500 kHz		3			dB
@ 1 MHz		1			dB
FI/MV Mode	FV/MI PSRR				
FORCE Pin					
@ 100 kHz		20			dB
@ 500 kHz		13			dB
@ 1 MHz		13			dB
IVMON Pin					
@ 100 kHz		18			dB
@ 500 kHz		10			dB
@ 1 MHz		7			dB

Force Voltage

Parameter	Symbol	Min	Typ	Max	Units
Input Voltage Range @ V _{INP}	V _{INP}	VEE + 2		VCC - 1.75	V
Input Bias Current	I _{INP}	-1	0	1	µA
Output Forcing Voltage (positive full scale current through REXT)	V _{FORCE}	VEE + 2.25		VCC - 4.25	V
Output Forcing Voltage (zero current through REXT)	V _{FORCE}	VEE + 2.25		VCC - 2.25	V
Output Forcing Voltage (negative full scale current through REXT)	V _{FORCE}	VEE + 4.25		VCC - 2.25	V
Voltage Accuracy					
Offset	V _{os}	-100		100	mV
Gain	FV Gain	.985		1.015	V/V
Linearity	FV INL	-0.025	±.01	+0.025	%FSR
Temperature Dependence (Note 6)					
Temperature Coefficient of Offset	ΔV _{os} /ΔT			-8	µV/°C
Temperature Coefficient of Gain	ΔFVGain/ΔT			-.2	µV/V/°C
Temperature Coefficient of Linearity	ΔFV INL/ΔT			-2x10 ⁻⁷	%FSR/°C

TEST AND MEASUREMENT PRODUCTS
DC Characteristics (continued)
Measure Current

Parameter	Symbol	Min	Typ	Max	Units
Current Measurement Range Range A Range B Range C Range D	I _{MEASURE}	-2 -20 -200 -2		2 20 200 2	µA µA µA mA
Current Measurement Accuracy Measure Current Offset Gain Linearity (measured at IVMON) FORCE = VEE + 4.25 to VCC - 5.25V FORCE = VCC - 5.25 to VCC - 4.25V	V _{os} MI Gain MI INL	-150 .985		+150 1.015	mV
Common Mode Error	CM Error	-1.5		.05 .08	% FSR % FSR
Common Mode Linearity FORCE = VEE + 4.25V to VCC - 4.25V	ΔCM Error	-.05		.05	%FSR
Temperature Dependence (Note 6) Temperature Coefficient of Offset Temperature Coefficient of Gain Temperature Coefficient of Linearity	ΔV _{os} /ΔT ΔMI Gain/ΔT ΔMI INL/ΔT		-60 2 5x10 ⁻⁷		µV/°C µV/V°C %FSR/°C

Force Current

Parameter	Symbol	Min	Typ	Max	Units
Input Voltage Range @ IVIN	V _{IVIN}	-2.25		2.25	V
Input Bias Current	I _{IVIN}	-1	0	1	µA
Output Forcing Current Range A Range B Range C Range D	I _{FORCE}	-2 -20 -200 -2		2 20 200 2	µA µA µA mA
Compliance Voltage Range Positive Full-Scale Current through REXT Zero Current through REXT Negative Full-Scale Current through REXT	V _{FORCE}	VEE + 2.25 VEE + 2.25 VEE + 4.25		VCC - 4.25 VCC - 2.25 VCC - 2.25	V V V
Current Accuracy Offset Gain Linearity (measured at IVMON) FORCE = VEE + 4.25 to VCC - 5.25V FORCE = VCC - 5.25 to VCC - 4.25V	I _{os} FI Gain FI INL	-.5 .985		5 1.015	% FSR
Common Mode Error (Note 4)	CM Error	-3		3	mV/V
Common Mode Linearity FORCE = VEE + 4.25V to VCC - 4.25V	ΔCM Error	-.05		.05	%FSR
Temperature Dependence (Note 6) Temperature Coefficient of Offset Temperature Coefficient of Gain Temperature Coefficient of Linearity	ΔV _{os} /ΔT ΔFI Gain/ΔT ΔFI INL/ΔT		7x10 ⁻³ 2 1x10 ⁻⁸		µV/°C µV/V°C %FSR/V

TEST AND MEASUREMENT PRODUCTS
DC Characteristics (continued)
Measure Voltage

Parameter	Symbol	Min	Typ	Max	Units
Voltage Measurement Range	V_{SENSE}	$VEE + 2.25$		$VCC - 2.25$	V
Voltage Measurement Accuracy					
Measure Voltage Offset	V_{os}	-100		100	mV
Gain	$MV\ Gain$.985		1.015	
Linearity	$MV\ INL$	-.025	$\pm .01$.025	%FSR
Temperature Dependence (Note 6)					
Temperature Coefficient of Offset	$\Delta V_{os}/\Delta T$		21		$\mu V/\text{ }^{\circ}\text{C}$
Temperature Coefficient of Gain	$\Delta MV\ Gain/\Delta T$		0.35		$\mu V/V/\text{ }^{\circ}\text{C}$
Temperature Coefficient of Linearity	$\Delta MV\ INL/\Delta T$		-9×10^{-8}		%FSR/ $\text{ }^{\circ}\text{C}$

Digital Inputs (FV/FI*, MI/MV*, RS0, RS1, DISABLE, I_FCSEL, E_FCSEL, E_SNSEL, SV_SEL)

Parameter	Symbol	Min	Typ	Max	Units
Input Low Level	V_{IL}			0.8	V
Input High Level	V_{IH}	2.0			V
Input Bias Current @ OV to VDD	I_{IN}	-1	0	1	μA

External Force & Sense Switches

Parameter	Symbol	Min	Typ	Max	Units
External Force Switches					
Usable Input Voltage Range @ E_FC_IN	VE_FC_IN	VEE		VCC	V
Usable Input Current Range @ E_FC_IN	IE_FC_IN	-25		25	mA
On-resistance	$RON_E_FC_IN$		45	55	Ω
Leakage Current @ E_FC_IN					
Switch Open ($E_FC_SEL = 0$)	I_{leak}	-10		10	nA
Switch Closed ($E_FC_SEL = 1$)	I_{leak}	-10		10	nA
Input Capacitance	CE_FC_IN		28		pF
External Sense Switches					
Usable Input Voltage Range @ E_SN_IN	VE_SN_IN	VEE		VCC	V
On-resistance	$RON_E_SN_IN$		1000	1200	Ω
Leakage Current					
Switch Open ($E_SN_SEL = 0$)	I_{leak}	-10		10	nA
Switch Closed ($E_SN_SEL = 1$)	I_{leak}	-10		10	nA
HiZ (Switches Open) Leakage Current (Note 5)					
VFORCE = -3V to 13V, FV/FI* = 0	I_{leak}	-10		10	nA
Combined Capacitance of FORCE and SENSE Pins (Notes 2, 5)	C_{FRC_SNS}			14	pF

TEST AND MEASUREMENT PRODUCTS
DC Characteristics (continued)
Analog MUX

Parameter	Symbol	Min	Typ	Max	Units
Usable Input Voltage Range	Vin	VEE		VCC	V
On-resistance (Force) @ 500 μ A	R _{ON_MUX}		600	1000	Ω
On-resistance Variability (Across full VEE to VCC Range)	ΔR_{ON_MUX}			400	Ω
Leakage Current	I _{LEAK_MUX}			200	nA

IVMON

Parameter	Symbol	Min	Typ	Max	Units
Leakage in DISABLED Mode @ IVMON = -2.2V to +13V	I _{LEAK_IVMON}	-100		+100	nA
IVMON Output Impedance	R _{OUT}		500		Ω

Comparator

Parameter	Symbol	Min	Typ	Max	Units
IVMAX Voltage Range	IVMAX	VEE + 1.75		VCC - 1.75	V
IVMIN Voltage Range	IVMIN	VEE + 1.75		VCC - 1.75	V
Comparator Offset (IVMIN, IVMAX)	V _{os}	-100		+100	mV
Input Bias Current at IVMIN, IVMAX	I _{bias}	-1		+1	μ A

Digital Outputs (DUTLTH, DUTGTL)

Parameter	Symbol	Min	Typ	Max	Units
Output Low Level @ I _{OL} = -200 μ A	V _{OL}			400	mV
Output High Level @ I _{OH} = 200 μ A	V _{OH}	2.4		VDD	V

Above DC Characteristic specifications are guaranteed over full Recommended Operating Condition ranges unless otherwise noted.

- Note 1: Under no load conditions.
- Note 2: Guaranteed by design and characterization. Not production tested.
- Note 3: PSRR is tested from VCC/VEE supplies to FORCE and IVMON outputs. Characterized in FV/MI and FI/MV modes.
- Note 4: The mV/V units shown are derived as follows: (Δ offset current * range resistance) / Δ output force voltage.
- Note 5: Test Conditions: E_FC_SEL = I_FC_SEL = 0; FV/FI* = 0, FORCE and SENSE tied together over full-scale voltage range.
- Note 6: Temperature coefficients are valid over a 25°C to 65°C case temperature range unless otherwise noted.

TEST AND MEASUREMENT PRODUCTS
AC Characteristics
Force Voltage/Measure Current

Parameter	Symbol	Min	Typ	Max	Units
FORCE Output Voltage Settling Time (Notes 1, 2) To 0.1% of final value (CFORCE/SENSE = 100 pF) Range A Ranges B, C, D	tsettle		45	530 110	μs μs
Measured Current Settling Time (Notes 1, 4) To 0.1% of final value (CFORCE/SENSE = 100 pF) Range A Ranges B, C, D	tsettle		50	1.4 110	ms μs
To 2% of final value (CFORCE/SENSE = 150 pF) Ranges B, C, D	tsettle		28	110	μs
I/V Monitor (Note 3) DISABLE True to HiZ Propagation Delay DISABLE False to Active Propagation Delay	t _z t _{oe}			60 60	ns ns
Force Amp Saturation Recovery Time	t _{sat}		11	40	μs
Capacitive Loading Range for Stable Operation (FORCE)	C _{LOAD}			4	nF

Force Current/Measure Voltage

Parameter	Symbol	Min	Typ	Max	Units
FORCE Output Current Settling Time (Notes 1, 5) (To 0.1% of final value) Range A Ranges B, C, D	tsettle			2 250	ms μs
SENSE (Measure) Voltage Settling Time (Notes 1, 6) (To 0.1% of final value) Range A Ranges B, C, D	tsettle			1.75 225	ms μs
I/V Monitor (Note 3) DISABLE True to HiZ Propagation Delay DISABLE False to Active Propagation Delay	t _z t _{oe}			60 60	ns ns
Force Amp Saturation Recovery Time	t _{sat}		11	40	μs
Capacitive Loading Range for Stable Operation (FORCE)	C _{LOAD}			4	nF

TEST AND MEASUREMENT PRODUCTS
AC Characteristics (*continued*)
Analog MUX

Parameter	Symbol	Min	Typ	Max	Units
Switch Propagation Delay (Note 3)	tpd			60	ns

Comparator

Parameter	Symbol	Min	Typ	Max	Units
Propagation Delay	tpd			25	μs

AC Test Conditions (unless otherwise noted): COMP1 to COMP2 = 22 pF, COMP3 = 100 pF to Ground, COMP4 = 47 pF to RES_IN, Capacitive Load at FORCE/SENSE combined output = 150 pF to GND, Capacitive Load at IVMON = 2 nF to GND,

Note 1: Settling times are not production tested. Guaranteed by characterization.

Note 2: Measured from 2V step at VINP to FORCE output.

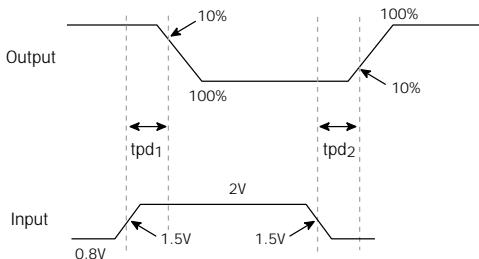
Note 3: Not production tested. Guaranteed by characterization.

Test Conditions for Characterization:

1. 15 pF load on output

2. input signal has 5 ns rise/fall time

3. tpd is defined as the difference between the time when the input crosses 1.5V to when the output changes 10% (of the total change) from the initial voltage level. (see timing diagram below).



Note 4: Measured from 2V step at VINP to IVMON output.

Note 5: Measured from 2V step at IVIN to FORCE output.

Note 6: Measured from 2V step at IVIN to IVMON output.

TEST AND MEASUREMENT PRODUCTS

Ordering Information

Model Number	Package
E4707BBG	180 Lead 12 mm x 12 mm FlexBGA
EVM4707BBG	Edge4707 Evaluation Module



This device is ESD sensitive. Care should be taken when handling and installing this device to avoid damaging it.

Contact Information

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TEST AND MEASUREMENT PRODUCTS

Revision History

Current Revision Date: October 3, 2002**Previous Revision Date:** June 20, 2002

Page#	Section Name	Description of Change
all	Status	Change from "Target" to "Preliminary"
11	Circuit Description	<i>Add:</i> Power Supply Sequencing Section
18	Power Supplies	Break down Power Supply Rejection Ratio into FV/MI & FI/MV Modes
18-22	DC & AC Characteristics	Replace all "TBDs" with numbers